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Kind regards,

Team Nexperia

PDTA123T series

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = open

Rev. 02 — 3 September 2009

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET) family.

Table 1. Product overview

| Type number | Package | NPN complement | | |
|--------------|---------|----------------|----------|-----------|
| | NXP | JEITA | JEDEC | |
| PDTA123TE | SOT416 | SC-75 | - | PDTC123TE |
| PDTA123TK | SOT346 | SC-59A | TO-236 | PDTC123TK |
| PDTA123TM | SOT883 | SC-101 | - | PDTC123TM |
| PDTA123TS[1] | SOT54 | SC-43A | TO-92 | PDTC123TS |
| PDTA123TT | SOT23 | - | TO-236AB | PDTC123TT |
| PDTA123TU | SOT323 | SC-70 | - | PDTC123TU |

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2)

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Controlling IC inputs

- Cost-saving alternative for BC857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------|---------------------------|------------|------|-----|------|-----------|
| V_{CEO} | collector-emitter voltage | open base | - | - | -50 | V |
| Io | output current | | - | - | -100 | mA |
| R1 | bias resistor 1 (input) | | 1.54 | 2.2 | 2.86 | $k\Omega$ |



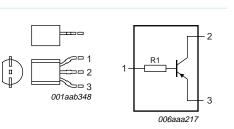
2. Pinning information

Table 3. Pinning

| Pin | Description | Simplified outline | Symbol |
|-------|--------------------|--------------------|--------|
| SOT54 | | | |
| 1 | input (base) | | |
| 2 | output (collector) | | 2 |
| 3 | GND (emitter) | 001aab347 | 1 R1 3 |

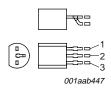
| SOT54A | | |
|--------|--------------------|--|
| 1 | input (base) | |
| 2 | output (collector) | |

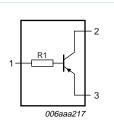
3 GND (emitter)



SOT54 variant

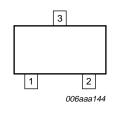
| 1 | input (base) |
|---|--------------------|
| 2 | output (collector) |
| 3 | GND (emitter) |

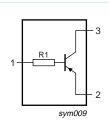




SOT23; SOT323; SOT346; SOT416

| 1 | input (base) |
|---|--------------------|
| 2 | GND (emitter) |
| 3 | output (collector) |

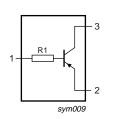




SOT883

| 1 | input (base) |
|---|--------------------|
| 2 | GND (emitter) |
| 3 | output (collector) |





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3. Ordering information

Table 4. Ordering information

| Type number | Package | | | | | |
|--------------|---------|---|---------|--|--|--|
| | Name | Description | Version | | | |
| PDTA123TE | SC-75 | plastic surface mounted package; 3 leads | SOT416 | | | |
| PDTA123TK | SC-59A | plastic surface mounted package; 3 leads | SOT346 | | | |
| PDTA123TM | SC-101 | leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm | SOT883 | | | |
| PDTA123TS[1] | SC-43A | plastic single-ended leaded (through hole) package; 3 leads | SOT54 | | | |
| PDTA123TT | - | plastic surface mounted package; 3 leads | SOT23 | | | |
| PDTA123TU | SC-70 | plastic surface mounted package; 3 leads | SOT323 | | | |

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9)

4. Marking

Table 5. Marking codes

| 9 | |
|-------------|-----------------------------|
| Type number | Marking code ^[1] |
| PDTA123TE | 2A |
| PDTA123TK | GA |
| PDTA123TM | FA |
| PDTA123TS | TA123T |
| PDTA123TT | ZL* |
| PDTA123TU | *1S |

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Mi | n Max | Unit |
|------------------|---------------------------|---|--------|--------|------|
| V_{CBO} | collector-base voltage | open emitter | - | -50 | V |
| V_{CEO} | collector-emitter voltage | open base | - | -50 | V |
| V_{EBO} | emitter-base voltage | open collector | - | -5 | V |
| Io | output current | | - | -100 | mA |
| I _{CM} | peak collector current | single pulse; $t_p \le 1 \text{ ms}$ | - | -100 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 ^{\circ}C$ | | | |
| | SOT416 | | [1] - | 150 | mW |
| | SOT346 | | [1] - | 250 | mW |
| | SOT883 | | [2][3] | 250 | mW |
| | SOT54 | | [1] - | 500 | mW |
| | SOT23 | | [1] - | 250 | mW |
| | SOT323 | | [1] - | 200 | mW |
| T _{stg} | storage temperature | | -6 | 5 +150 | °C |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -6 | 5 +150 | °C |

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------|---|-------------|--------------|-----|-----|------|
| $R_{th(j-a)}$ | thermal resistance from junction to ambient | in free air | | | | |
| | SOT416 | | <u>[1]</u> - | - | 833 | K/W |
| | SOT346 | | <u>[1]</u> - | - | 500 | K/W |
| | SOT883 | | [2][3] | - | 500 | K/W |
| | SOT54 | | <u>[1]</u> - | - | 250 | K/W |
| | SOT23 | | <u>[1]</u> - | - | 500 | K/W |
| | SOT323 | | <u>[1]</u> - | - | 625 | K/W |

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with $60~\mu m$ copper strip line, standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

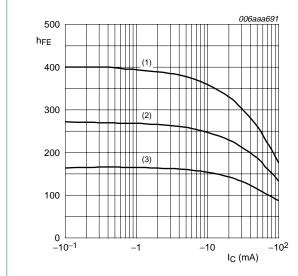
^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

7. Characteristics

Table 8. Characteristics

T_{amb} = 25 °C unless otherwise specified

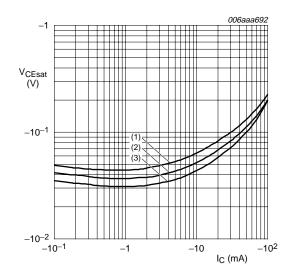
| unio | <u>'</u> | | | | | |
|--------------------|--------------------------------------|--|------|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| I_{CBO} | collector-base cut-off current | $V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$ | - | - | -100 | nA |
| I_{CEO} | collector-emitter cut-off | $V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$ | - | - | -1 | μΑ |
| | current | $V_{CE} = -30 \text{ V}; I_B = 0 \text{ A};$ $T_j = 150 ^{\circ}\text{C}$ | - | - | -50 | μΑ |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$ | - | - | -100 | nA |
| h _{FE} | DC current gain | $V_{CE} = -5 \text{ V}; I_{C} = -20 \text{ mA}$ | 30 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = -10 \text{ mA}; I_B = -0.5 \text{ mA}$ | - | - | -150 | mV |
| R1 | bias resistor 1 (input) | | 1.54 | 2.2 | 2.86 | kΩ |
| C _c | collector capacitance | $V_{CB} = -10 \text{ V}; I_E = I_e = 0 \text{ A};$ f = 1 MHz | - | - | 3 | pF |
| | | | | | | |





- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values

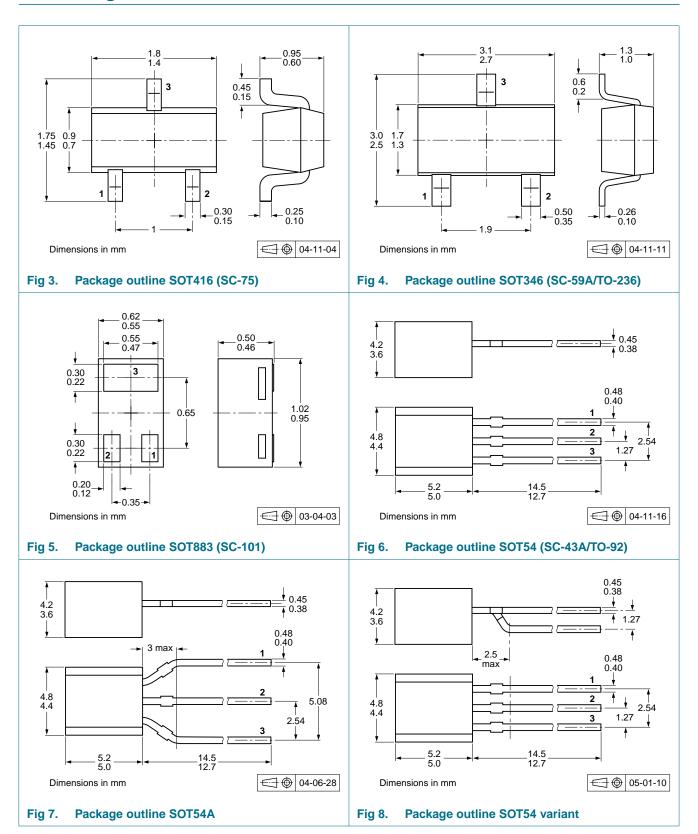


$$I_{\rm C}/I_{\rm B} = 20$$

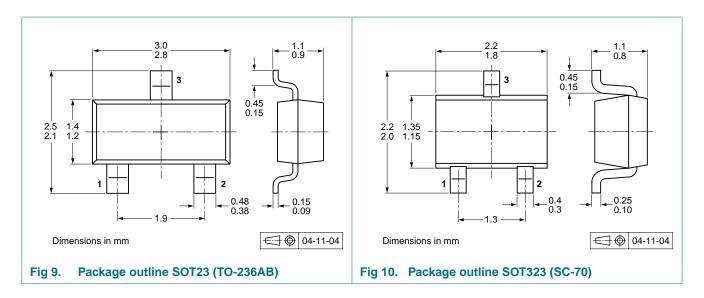
- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

8. Package outline



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9. Packing information

Table 9. Packing methodsThe indicated -xxx are the last three digits of the 12NC ordering code. [1]

| Type number | Package | Description | Packir | Packing quantity | | |
|-------------|---------------|--------------------------------|--------|------------------|-------|--|
| | | | 3000 | 5000 | 10000 | |
| PDTA123TE | SOT416 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |
| PDTA123TK | SOT346 | 4 mm pitch, 8 mm tape and reel | -115 | - | -135 | |
| PDTA123TM | SOT883 | 2 mm pitch, 8 mm tape and reel | - | - | -315 | |
| PDTA123TS | SOT54 | bulk, straight leads | - | -412 | - | |
| | SOT54A | tape and reel, wide pitch | - | - | -116 | |
| | | tape ammopack, wide pitch | - | - | -126 | |
| | SOT54 variant | bulk, delta pinning | - | -112 | - | |
| PDTA123TT | SOT23 | 4 mm pitch, 8 mm tape and reel | -215 | | -235 | |
| PDTA123TU | SOT323 | 4 mm pitch, 8 mm tape and reel | -115 | | -135 | |

^[1] For further information and the availability of packing methods, see Section 12.

PDTA123T series

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PNP resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

10. Revision history

Table 10. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|---|--------------------|---------------|----------------|--|--|
| PDTA123T_SER_2 | 20090903 | Product data sheet | - | PDTA123T_SER_1 | | |
| Modifications: | This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content. | | | | | |
| PDTA123T_SER_1 | 20060307 | Product data sheet | - | - | | |

11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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PDTA123T series

PNP resistor-equipped transistors; R1 = 2.2 k Ω , R2 = open

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